

NOTE

TRANSIL™/TRISIL™ COMPARISON

A. Bremond

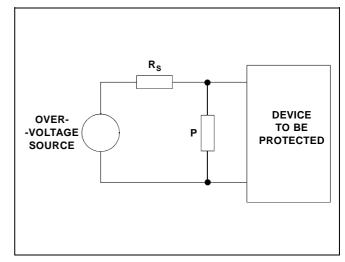
1. INTRODUCTION

To protect a sensitive device there are two different approaches.

The first one is to use series protectors, the second one parallel suppressors. technologies used in both cases are such that the series devices are suitable for long duration surges, while parallel protectors are very efficient for the high current short duration stresses which represent the great majority of cases.

For the parallel protection solutions, two philosophies can be used. The first one is represented by a breakdown based device and the second one by a breakover based protector, respectively known as the Transil and the Trisil.

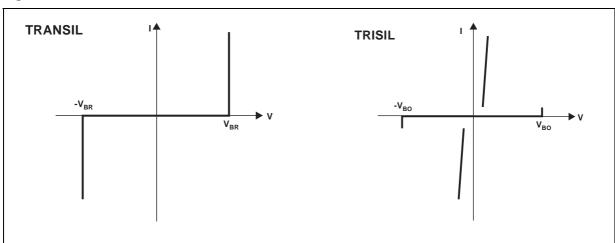
Figure1A: Classical schematic of parallel protection



2. TRANSIL / TRISIL COMPARISON

2.1. Electrical characteristics

Figure 1B: Electrical characteristics



The Transil is a clamping device which suppresses all overvoltages above the breakdown voltage (VBR)

The Trisil is a crowbar device which switches on when overvoltages rise up to the breakover voltage (± V_{BO}).

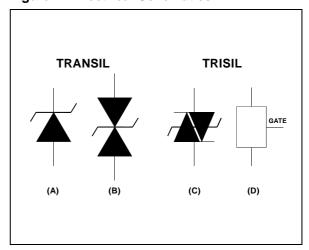
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2.3. Electrical Schematics.

The Transil may be unidirectional (Fig. 2 (A)) or bidirectional (Fig. 2 (B)). In unidirectional form, it operates as a clamping device in one sense and like a rectifier in the other.

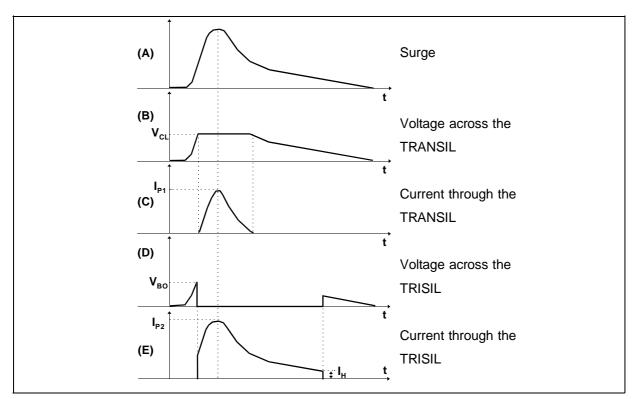
The Trisil may be designed to function with a fixed breakover value (fig. 2 (c)) or a value which can be programmed by the gate (fig.2(D)).

Figure 2: Electrical Schematics



2.3. Electrical Behaviour.

Figure 3: Electrical behaviour in a Transil and a Trisil



For the same surge (A), figure 3 shows the electrical behaviour of a Transil and a Trisil.

The parts (B) and (C) of figure 3 give the voltage across the Transil and the current through it. It is important to note that the current flows through the protection device only during the clamping phase. This fact has to be taken into account when the protector is chosen, because the

current duration is always shorter than that of the overvoltage surge.

The parts (D) and (E) of figure 3 relate to the Trisil behaviour. In this case the device fires when the voltage across it reaches the breakdown voltage V_{BO} and remains in the on-state until the current falls under the holding value I_{H} . The current flows through the Trisil during all of the on-state phase.

2.4. Power dissipation

The dissipated power in both the Transil and the Trisil is due to the presence of voltage across and current through the protection device.

Note that for the same package, the current-handling capability of a Transil depends on the breakdown voltage, whereas this is not the case for a Trisil.

For example, with the CB429 package we have the Transil series 1.5 KE and the Trisil family TPB which have different behaviour in terms of current suppression.

Table 1: Current capabilities of Transil 1.5KE and Trisil TPB

	Current capability for 1ms wave			
	10V	62V	150V	220V
Transil 1.5KE	103A	17.7A	7.2A	4.6A
Trisil TPB		100A	100A	100A

As shown in table 1 the current rating of TPB devices is always 100 A whatever the V_{BR} value, while it depends on the V_{BR} for the 1.5KE series.

3. SUMMARY

Table 2: Transil/Trisil Summary

	TRANSIL	TRISIL
TYPE OF ACTION	CLAMPING	CROWBAR
ELECTRICAL CHARACTERISTICS	-V _{ax} V	-V ₈₀ V ₈₀
SCHEMATICS	OR A	OR
ELECTRICAL BEHAVIOUR	V _{CL}	V _{B0}
ACTION START	Vsurge > V _{BR}	Vsurge > V _{BO}
ACTION STOP	Vsurge < V _{BR}	I < Holding Current

Table 3: Transil/Trisil distinctive advantages

TRANSIL	TRISIL
No short - circuit across low - impedance lines , eg - power - supply.	Greater power handling due to lower voltage across terminals.
No need to ensure device switch - off after transient subsides.	Available with program- mable breakover voltage.

Tables 2 and 3 summarize the different behaviour and advantages of both Transil and Trisil devices. It is not possible to say "Transils are better than Trisils" or the opposite, only that their application areas are different. SGS-THOMSON produces both types of devices meeting the widest protection requirements range.

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